

## Field Programmable Blank Oscillator

Series **CPP**

- Programmed with the PG-3000, PG-3100 field oscillator programming instrument within seconds
- Can be programmed twice
- Standard Package Options
- Also available in 2.7 V



## Part Numbering Example: CPP C 1 L Z - A5 B6 - XX.XXXX TS

| CPP    | C                   | 1                                                                                                             | L                                  | Z                                             | A5                                                                             | B6                                            | XX.XXXX            | TS                            |
|--------|---------------------|---------------------------------------------------------------------------------------------------------------|------------------------------------|-----------------------------------------------|--------------------------------------------------------------------------------|-----------------------------------------------|--------------------|-------------------------------|
| SERIES | OUTPUT              | PACKAGE STYLE                                                                                                 | VOLTAGE                            | ADDED FEATURES                                | OPERATING TEMP.                                                                | STABILITY                                     | FREQUENCY          | TRI-STATE                     |
| CPP    | C = CMOS<br>T = TTL | 1 = Full Size<br>4 = Half Size<br>5 = 3.2X5 Ceramic<br>7 = 5X7 Ceramic<br>8 = PLASTIC SMD<br>8B = PLASTIC SMD | Blank = 5V<br>L = 3.3 V<br>R = 2.7 | Blank = Bulk<br>T = Tube<br>Z = Tape and Reel | Blank = 0°C +70°C<br>A3 = -55°C +155°C<br>A5 = -20°C +70°C<br>A7 = -40°C +85°C | B6 = ±100 ppm<br>BP = ±50 ppm<br>BR = ±25 ppm | 0.500 ~133.000 MHz | TS = Tri-State<br>PD=PowerDwn |

## Specifications:

| Description                                                       | Min                | Typ        | Max               | Unit              |
|-------------------------------------------------------------------|--------------------|------------|-------------------|-------------------|
| <b>Frequency Range:</b><br>Programmable to Any Discrete Frequency | 0.5                |            | 133.000           | MHz               |
| <b>Available Stability Options:</b>                               | -100<br>-50<br>-25 |            | 100<br>50<br>25   | ppm<br>ppm<br>ppm |
| <b>Programmable Supply Voltage:</b><br>(1–133 MHz)<br>(1–100 MHz) | 4.5<br>3.0         | 5.0<br>3.3 | 5.5<br>3.6        | V<br>V            |
| <b>Operating Temperature Range Options:</b>                       | 0<br>-20<br>-40    |            | +70<br>+70<br>+85 | °C<br>°C<br>°C    |
| <b>Storage Temperature:</b>                                       | -55                |            | +125              | °C                |
| Aging (PPM/Year)<br>Ta=25°C, Vdd=5/3.3V                           |                    |            | ±5                |                   |
| <b>Programmable Output Level:</b> TTL/CMOS                        |                    |            |                   |                   |
| <b>Packaging:</b> Tape and Reel (1K per Reel)<br>Tube             |                    |            |                   |                   |

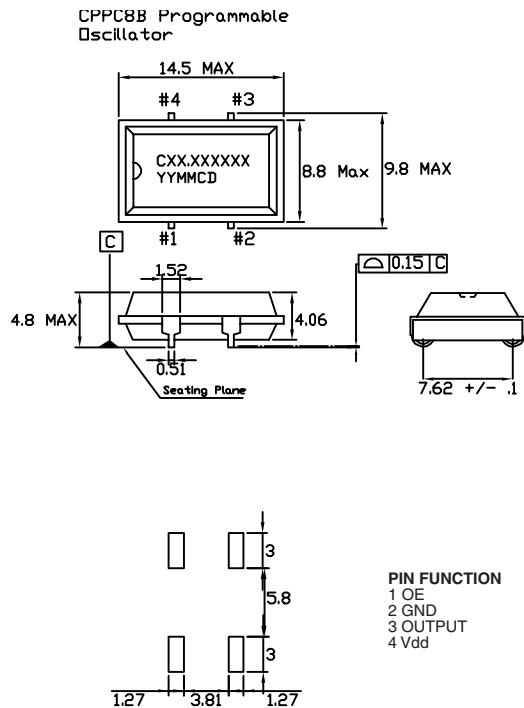
## Operating Conditions:

| Description                                                                                                                                                                        | Min | Max                  | Unit                 |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|----------------------|----------------------|
| Vdd Supply Voltage                                                                                                                                                                 | 3.0 | 5.5                  | V                    |
| C <sub>TTL</sub> Max Capacitive Load on outputs for TTL levels<br>4.5V–5.5V Vdd ≤ 40 MHz<br>4.5V–5.5V Vdd > 40–133 MHz                                                             |     | 50<br>25             | pF<br>pF             |
| C <sub>CMOS</sub> Max Capacitive Load on outputs for CMOS levels<br>4.5V–5.5V Vdd, ≤ 66 MHz<br>4.5V–5.5V Vdd, >66–133 MHz<br>3.0V–3.6V Vdd, ≤ 40 MHz<br>3.0V–3.6V Vdd, >40–100 MHz |     | 50<br>25<br>30<br>15 | pF<br>pF<br>pF<br>pF |

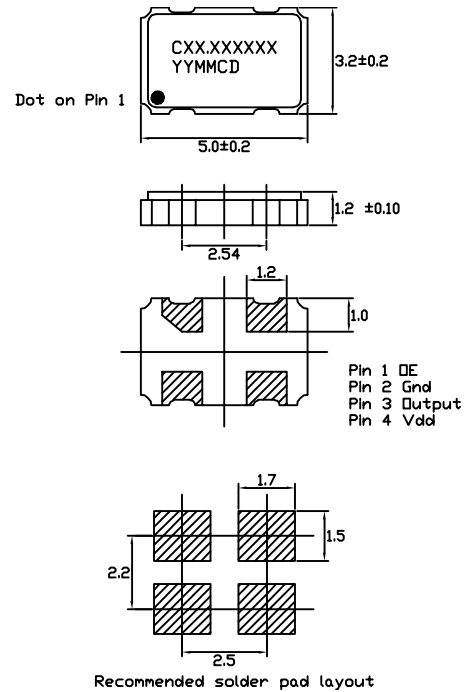
# Field Programmable Blank Oscillator

**Note:** *Bypass Vdd to GND with a 0.01  $\mu$ F capacitor*

## Style 8B Plastic SMD



## Style 5 3.2x5 Ceramic SMD

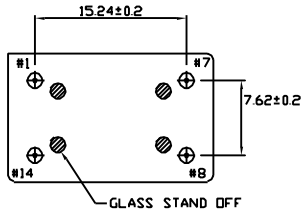
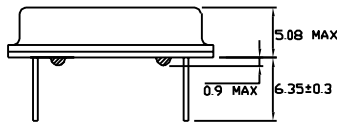
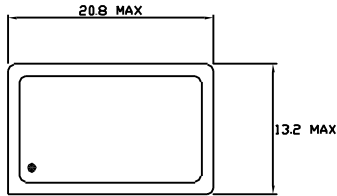


# Field Programmable Blank Oscillator

**Note:** *Bypass Vdd to GND with a 0.01  $\mu$ F capacitor*

## Style 1 Full Size 14 Pin Dip

STYLE 1 FULL SIZE 14 PIN DIP



**PIN FUNCTION**  
1 CONTROL  
7 GND  
8 OUTPUT  
14 Vdd

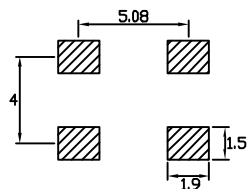
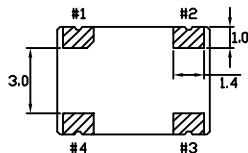
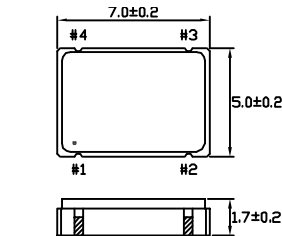
## Style 4 Half Size 8 Pin Dip

STYLE 4 HALFSIZE 8 PIN DIP



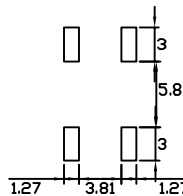
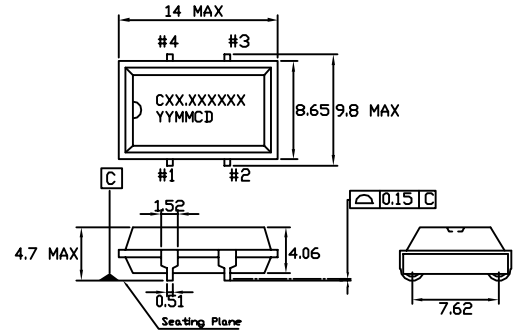
**PIN FUNCTION**  
1 CONTROL  
4 GND  
5 OUTPUT  
8 Vdd

## Style 7 5x7 Ceramic SMD



**PIN FUNCTION**  
1 CONTROL  
2 GND  
3 OUTPUT  
4 Vdd

## Style 8 Plastic SMD



**PIN FUNCTION**  
1 CONTROL  
2 GND  
3 OUTPUT  
4 Vdd

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## Output Clock Switching Characteristics

| Description                                                      | TEST CONDITIONS                                              | Min | Typ | Max  | Unit |
|------------------------------------------------------------------|--------------------------------------------------------------|-----|-----|------|------|
| <b>Duty Cycle:</b><br>TTL @ 1.4 V<br>4.5-5.5 Vdd                 | ≤ 50 MHz, C <sub>L</sub> = 50 pF                             | 45  |     | 55   | %    |
|                                                                  | 50–66 MHz, C <sub>L</sub> = 15 pF                            | 45  |     | 55   | %    |
|                                                                  | 66–125 MHz, C <sub>L</sub> = 25 pF                           | 40  |     | 60   | %    |
|                                                                  | 125–133 MHz, C <sub>L</sub> = 15 pF                          | 40  |     | 60   | %    |
| <b>Duty Cycle:</b><br>CMOS @ Vdd/2<br>4.5-5.5 Vdd<br>3.0–3.6 Vdd | ≤ 66 MHz, C <sub>L</sub> ≤ 25 pF                             | 45  |     | 55   | %    |
|                                                                  | 66–125 MHz, C <sub>L</sub> ≤ 25 pF                           | 40  |     | 60   | %    |
|                                                                  | 125–133 MHz, C <sub>L</sub> ≤ 15 pF                          | 40  |     | 60   | %    |
|                                                                  | ≤ 40 MHz, C <sub>L</sub> ≤ 30 pF                             | 45  |     | 55   | %    |
|                                                                  | 40-100 MHz, C <sub>L</sub> ≤ 15 pF                           | 40  |     | 60   | %    |
| <b>Output Clock Rise/Fall</b>                                    | 0.8V–2.0V, 4.5-5.5 Vdd, C <sub>L</sub> = 50                  |     |     | 1.8  | ns   |
|                                                                  | 0.8V–2.0V, 4.5-5.5 Vdd, C <sub>L</sub> = 25                  |     |     | 1.2  | ns   |
|                                                                  | 0.8V–2.0V, 4.5-5.5 Vdd, C <sub>L</sub> = 15                  |     |     | 0.9  | ns   |
|                                                                  | 0.2–0.8Vdd, 4.5-5.5 Vdd, C <sub>L</sub> = 50                 |     |     | 3.4  | ns   |
|                                                                  | 0.2–0.8Vdd, 3.0–3.6 Vdd, C <sub>L</sub> = 30                 |     |     | 4.0  | ns   |
|                                                                  | 0.2–0.8Vdd, 3.0–3.6 Vdd, C <sub>L</sub> = 15                 |     |     | 2.4  | ns   |
| <b>Start Up Time</b>                                             | From power on                                                |     |     | 2    | ms   |
| <b>Power Down Delay Time</b><br>Synchronous<br>Asynchronous      | PWR_DWN pin LOW to output Hi-Z                               |     | T/2 | T+10 | ns   |
|                                                                  |                                                              |     | 10  | 15   | ns   |
| <b>Output Disable Time</b><br>Synchronous<br>Asynchronous        | OE pin LOW to output Hi-Z<br>T = Frequency oscillator period |     | T/2 | T+10 | ns   |
|                                                                  |                                                              |     | 10  | 15   | ns   |
| <b>Output Enable Time</b>                                        |                                                              |     |     | 100  | ns   |
| <b>RMS Period Jitter:</b>                                        | ≤ 33.000 MHz                                                 |     | 40  | 50   | ps   |
|                                                                  | > 33.000, MHz                                                |     | 30  | 40   | ps   |
| Peak to Peak *                                                   | ≤ 33.000 MHz                                                 |     | 100 | 250  | ps   |
|                                                                  | > 33.000 MHz                                                 |     | 75  | 175  | ps   |

\* Jitter tested at > 1,000,000 samples, exceeding JEDEC std JESD65.



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## Electrical Characteristics

| Description                                           | TEST CONDITIONS                                    | Min                  | Typ | Max                | Unit |
|-------------------------------------------------------|----------------------------------------------------|----------------------|-----|--------------------|------|
| <b>Input Characteristics (Pin 1):</b>                 |                                                    |                      |     |                    |      |
| V <sub>IL</sub> , Low-Level Input Voltage             | 4.5–5.5V V <sub>dd</sub>                           |                      |     | 0.8                | V    |
| TO DISABLE OUTPUT                                     | 3.0–3.6V V <sub>dd</sub>                           |                      |     | 0.2V <sub>dd</sub> | V    |
| V <sub>IH</sub> , High-Level Input Voltage            | 4.5–5.5V V <sub>dd</sub>                           | 2.0                  |     |                    | V    |
| TO ENABLE OUTPUT OPEN                                 | 3.0–3.6V V <sub>dd</sub>                           | 0.7V <sub>dd</sub>   |     |                    |      |
| I <sub>IL</sub> , Input Low Current                   | V <sub>IN</sub> = 0V                               |                      |     | 10                 | μA   |
| I <sub>IH</sub> , Input High Current                  | V <sub>IN</sub> = V <sub>dd</sub>                  |                      |     | 5                  | μA   |
| <b>Output Characteristics:</b>                        |                                                    |                      |     |                    |      |
| V <sub>OL</sub> , Low-Level Output Voltage            | 4.5V–5.5V V <sub>dd</sub> , 16 mA I <sub>OL</sub>  |                      |     | 0.4                | V    |
|                                                       | 3.0V–3.6V V <sub>dd</sub> , 8 mA I <sub>OL</sub>   |                      |     | 0.4                | V    |
| V <sub>OHTTL</sub> ,<br>High-level Output Voltage TTL | 4.5V–5.5V V <sub>dd</sub> , -16 mA I <sub>OL</sub> | 2.4                  |     |                    | V    |
| V <sub>OHCMOS</sub> ,<br>High-level CMOS Voltage      | 4.5V–5.5V V <sub>dd</sub> , -16 mA I <sub>OL</sub> | V <sub>dd</sub> -0.4 |     |                    | V    |
|                                                       | 3.0V–3.6V V <sub>dd</sub> , -8 mA I <sub>OL</sub>  | V <sub>dd</sub> -0.4 |     |                    | V    |
| <b>Power Supply Current:</b><br><b>(unloaded)</b>     | 4.5–5.5 V <sub>dd</sub> , OUTPUT FREQ ≤ 133 MHz    |                      |     | 45                 | mA   |
|                                                       | 3.0–3.6 V <sub>dd</sub> , OUTPUT FREQ ≤ 100 MHz    |                      |     | 25                 | mA   |
| <b>Standby Current:</b>                               |                                                    |                      | 10  | 50                 | μA   |
| <b>Pull-Up (Pin 1)</b>                                | 4.5–5.5 V <sub>dd</sub> , V <sub>IN</sub> = 0V     | 1.1                  | 3.0 | 8.0                | MΩ   |
|                                                       | 4.5–5.5 V <sub>dd</sub> , V <sub>IN</sub> = 0.7V   | 50                   | 100 | 200                | KΩ   |
| <b>Tri-State Leakage Current</b>                      | 5.0 V <sub>dd</sub>                                |                      | 20  |                    | μA   |
| <b>Output Enable Mode:</b>                            | Output is Tri-Stated                               |                      |     |                    |      |
| <b>Power Down Mode:</b>                               | Output is Tri-Stated.                              |                      |     |                    |      |

